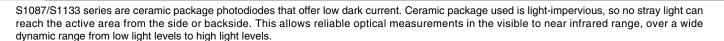
Si photodiode

S1087/S1133 series

Ceramic package photodiode with low dark current



Features

● S1087, S1133 : For visible range S1087-01, S1133-01: For visible to IR range S1133-14 : For visible to near IR range

Applications

- Exposure meter
- Illuminometer
- Camera auto exposure
- Stroboscope light control
- Copier
- Display light control
- Optical switch

■ General ratings / Absolute maximum ratings

Type No.	Dimensional			Absolute maximum ratings					
	outline/ Window material *	Active area size (mm)	Effective active area (mm²)	Reverse voltage V _R Max. (V)	Operating temperature Topr (°C)	Storage temperature Tstg (°C)			
S1087	①/V	1.3 × 1.3	1.6			-20 to +70			
S1087-01	@/R	1.3 * 1.3	1.6						
S1133	3/V			10	-10 to +60				
S1133-01	@/R	2.4 × 2.8	6.6						
S1133-14	⊕/K								

^{*} Window material R: resin coating, V: visual-compensation filter

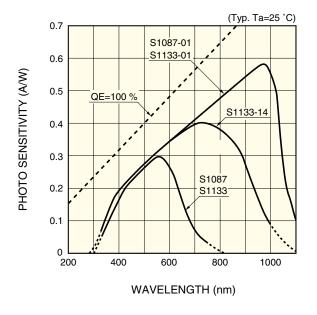
■ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

Type No.	Spectral response range λ	Peak sensitivity wavelength λp		oto sensit S (A/W) GaP LED	,	Infrared sensitivity ratio	Short circuit current Isc 100 lx	coefficient of Isc	Dark current ID VR=1 V Max.	of ID	tr	Terminal capacitance Ct VR=0 V f=10 kHz	resist Rs	unt tance sh 0 mV
	(nm)	(nm)			633 nm	(%)	(μA)	(%/°C)		(times/°C)		(pF)		Typ. (GΩ)
S1087	320 to 730	560	0.3	0.3	0.19	10	0.16	-0.01	10	1.12	0.5	200	10	250
S1087-01	320 to 1100	960	0.58	0.33	0.38	-	1.3	0.1						230
S1133	320 to 730	560	0.3	0.3	0.19	10	0.65	-0.01			2.5	700		100
S1133-01	320 to 1100	960	0.58	0.33	0.38	-	5.6	0.1						100
S1133-14	320 to 1000	720	0.4		0.37	-	3.4		20	1	0.5	200		50

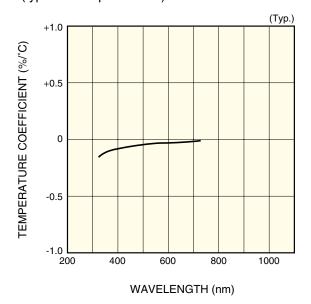


Si photodiode S1087/S1133 series

■ Spectral response

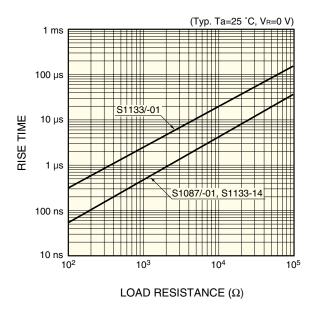


■ Photo sensitivity temperature characteristic (typical example: S1087)

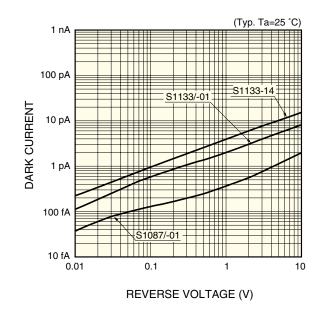


KSPDB0119EA KSPDB0063EB

■ Rise time vs. load resistance



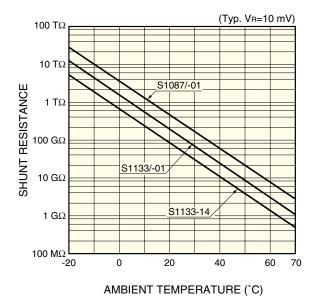
■ Dark current vs. reverse voltage



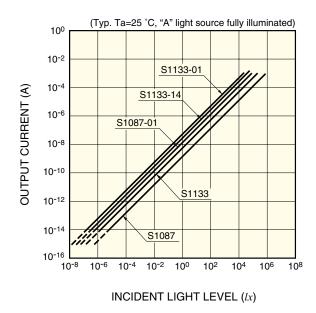
KSPDB0120EA KSPDB0121EA

Si photodiode S1087/S1133 series

■ Shunt resistance temperature characteristics



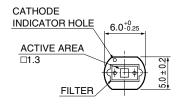
■ Short circuit current linearity

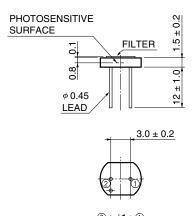


KSPDB0122EA KSPDB0123EA

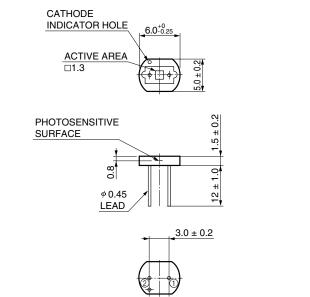
■ Dimensional outlines (unit: mm, tolerance unless otherwise noted: ±0.15)

① S1087



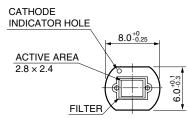


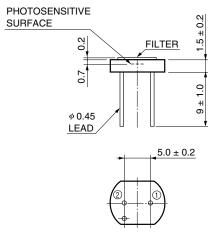
2 S1087-01



② ○-**|** ◆ ○ ① KSPDA0052EA

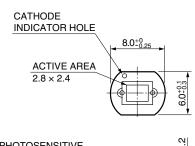
③ S1133

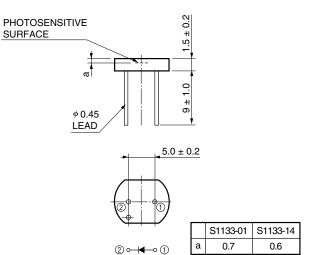




② ○ ★ ○ ①

4 S1133-01/-14





KSPDA0055E

KSPDA0053EA

KSPDA0054EA

HAMAMATSU

Information furnished by HAMAMATSU is believed to be reliable. However, no responsibility is assumed for possible inaccuracies or omissions. Specifications are subject to change without notice. No patent rights are granted to any of the circuits described herein. ©2001 Hamamatsu Photonics K.K.

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Hamamatsu City, 435-8558 Japan, Telephone: (81) 053-434-3311, Fax: (81) 053-434-5184, http://www.hamamatsu.com
U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P.O.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-9960, Fax: (1) 908-231-1218
Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 08152-23750, Fax: (49) 08152-2658
France: Hamamatsu Photonics France S.A.R.L.: 8, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10
United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777
North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-01
Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741